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SYNTHESIS AND PROPERTIES OF (TRIFLUOROMETHYL)TRICHLOROSILANE, A VERSATILE PRECURSOR FOR CF₃Si COMPOUNDS

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Summary

(Trifluoromethyl)trichlorosilane (I) has been prepared for the first time by the reaction of CF₃SiH(NMe₂)₂ (III) with HCl in dibutyl ether and, as a solution in CH₂Cl₂, by nucleophilic trifluoromethylation of SiCl₄ with CF₃Br/P(NEt₂)₃. From this solution, I may be isolated by HCl cleavage of its insoluble bis(pyridine) adduct (II). The aminosilane III was obtained from the reaction of HSi(Cl)(NMe₂)₂ with CF₃Br/P(NEt₂)₃. Selective substitution of I without attack on the CF₃Si moiety was achieved in high yields with SbF₃ (\rightarrow CF₃SiF₃), Ag(OCN) (\rightarrow CF₃Si(NCO)₃ (IV)), MeOH (\rightarrow CF₃Si(OMe)₃ (V)), HNMe₂ (\rightarrow CF₃Si(NMe₂)₃ (VI)), LiAlH₄ (\rightarrow CF₃SiH₃), MeMgBr (\rightarrow CF₃SiMe₃) and LiPh(\rightarrow CF₃SiPh₃ (VII)). With 2,2'-bipyridyl a 1/1 complex (VIII) was formed. The novel compounds I to VIII have been characterized by their IR, NMR and mass spectra, and for I a vibrational analysis including a normal coordinate treatment has been performed.

Introduction

Trifluoromethylsilicon compounds have only recently become easily available through nucleophilic trifluoromethylation of halosilanes with a reagent prepared from $(Et_2N)_3P$ and CF_3Br in a suitable solvent [1]. Though numerous claims for successful syntheses have been advanced [2], the only satisfactory route previously available to such trifluoromethylsilicon derivatives as CF_3SiF_3 [3] and CF_3SiH_3 [4] required preparation of CF_3SiF_2I [3] by the experimentally demanding insertion of SiF_2 into CF_3I . The observation that dialkylaminochlorosilanes could be converted into dialkylaminotrifluoromethylsilanes by means of $(Et_2N)_3P/CF_3Br$ and the SiN bond then cleaved by HCl to yield (trifluoromethyl)chlorosilanes without concomitant cleavage of the Si-C bond [5] seemed to provide an easy route to substantial quantities of these interesting compounds.

Our interest was directed towards the synthesis of the hitherto unknown compound CF_3SiCl_3 (I), which seemed like to act as trifunctional organosilicon halide from which a variety of CF_3Si derivatives could be prepared.

In the present contribution we describe two independent methods that we have found for the synthesis of CF_3SiCl_3 . In addition, some of the physical properties of I have been studied, and its ability to undergo substitution reactions with standard reagents evaluated.

Synthesis of CF₃SiCl₃ (I)

The nucleophilic trifluoromethylation with a reagent prepared from $P(NEt_2)_3$ and CF_3Br is assumed to involve a reactive intermediate such as $[P(NEt_2)_3Br]^+$ CF_3 which can displace a chloro atom from silicon to yield a CF_3St moiety [1], eq. 1:

$$\left| P(NEt_2)_3 Br \right|^{-1} CF_3^{-1} + \equiv Si - CI \rightarrow P(NEt_2)_3 CIBr + \equiv Si - CF_3^{-1}$$
(1)

While such a reaction appeared to provide a likely source of CF_3SiCl_3 (I), the actual procedure was not straightforward. It was noticed that the expected ligand scrambling between $P(NEt_2)_3$ and $SiCl_4$ (eq. 2) became important if the reaction was carried out near room temperature:

$$P(NEt_2)_3 + SiCl_4 \rightarrow P(NEt_2)_{3-n}Cl_n + SiCl_{4-n}(NEt_2)_n$$
(2)

Furthermore, it was found to be essential that I should be isolated from the reaction mixture at low temperature in vacuo because the $P(NEt_2)_3ClBr$ formed in accord with equation 1 tends to decompose I at higher temperatures. Finally, reaction 1 is strongly dependent on the solvent employed, and substantial yields of I were obtained only when CH_2Cl_2 was used. No reaction between $SiCl_4$ and the intermediate $[P(NEt_2)_3Br]CF_3$ occurred either in the absence of a solvent or in solvents such as n-heptane and toluene. Transamination according to eq. 2 was found in diglyme, while HCF_3 was formed in methyl ethyl ketone. Decomposition on work-up was noted when 1,2-dichloroethane or benzonitrile were employed. Thus, of the solvents inert to $SiCl_4$ only CH_2Cl_2 afforded I in reasonable yields (ca. $50f_{\epsilon}$), but the product was not pure. The closeness of the boiling points of CH_2Cl_2 (40°C) and CF_3SiCl_3 (41°C) frustrated all attempts to isolate I from the solvent, and so I and CH_2Cl_2 were separated chemically.

It is well known that silicon tetrahalides form complexes with suitable donor molecules, and a 1/2 complex of SiCl₄ with pyridine has been reported [6]. This complex can be sublimed in vacuo, and it has been shown that dissociation occurs in the gas phase [7]. In contrast to SiCl₄, CH₃SiCl₃ does not form a complex with pyridine at room temperature. We found that a white solid separated when pyridine was added to a solution of I in CH₂Cl₂. This solid, with the composition CF₃SiCl₃ + 2 pyridine (II), was sublimed in vacuo and cleaved quantitatively by liquid HCl according to eq. 3.

$$II + 2HCl \rightarrow I + 2 \text{ pyridine} \cdot HCl$$
(3)

The excess of HCl and I were removed from the involatile pyridinium chloride in vacuo, and pure I was obtained after evaporation of the residual HCl.

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While synthesizing CF_3SiH_3 via nucleophilic trifluoromethylation, we noticed that $HSiCl(NMe_2)_2$, easily prepared from $HSiCl_3$ and $HNMe_2$, is a particularly reactive species and gives a > 80% yield of $HSi(CF_3)(NMe_2)_2$ (III) upon trifluoromethylation with $CF_3Br/P(NEt_2)_3$ in benzonitrile at 0–20°C. The bis(amino)silane III is readily cleaved by HCl, the products depending on the conditions of the cleavage; reaction at $-96^{\circ}C$ gives CF_3SiHCl_2 in nearly quantitative yield (eq. 4),

$$III + 4HCl \rightarrow 2Me_2NH_2Cl + CF_3SiHCl_2$$
⁽⁴⁾

but only traces of I and $HSiCl_3$ were found. The amount of I formed in the course of reaction 4 increases if a solution of HCl in a hydrocarbon solvent is employed, while I is formed nearly quantitatively if III is treated with HCl in di-n-butyl ether (eq. 5). Only traces of CF_3SiHCl_2 were formed.

$$III + 5HCI \rightarrow 2Me_{2}NH_{2}CI + H_{2} + I$$
(5)

Thus, two syntheses for trifluoromethyltrichlorosilane are now available. If I can be used in solution, direct nucleophilic trifluoromethylation of $SiCl_4$ in CH_2Cl_2 is the method of choice. Pure I may be obtained via cleavage of the pyridine complex or by trifluoromethylation of $HSiCl(NMe_2)_2$ and subsequent reaction with HCl in di-n-butyl ether.

Properties of CF₃SiCl₃

At room temperature CF_3SiCl_3 is a colourless liquid which shows many similarities to $SiCl_4$. It is readily hydrolyzed, and the Si-C bond is quantitatively cleaved by aqueous alkali with formation of HCF₃. Its physical properties are set out in Table 1. In the gas phase thermal decomposition begins at ca. 120°C.

We have investigated the behaviour of I in a range of standard reactions of (organo)silicon halides. In these reactions chlorine was selectively replaced without rupture of the silicon-carbon bond.

(i) Halogen exchange

Compound I does not react with BF_3 during 3 h at 100°C, but it is converted into CF_3SiF_3 [3] by treatment with SbF_3 . In accord with the position of Cl in the conversion series [8], I reacts with AgOCN to yield the novel compound $CF_3Si(NCO)_3$ (IV).

(ii) Alkoxides and amides

The Cl atoms in I may be replaced by OR and NR_2 groups in the same way as those in MeSiCl₃ and SiCl₄. Reaction with MeOH and Me₂NH gave the first trifluoromethylsilicon trialkoxide CF₃Si(OMe)₃ (V) and trifluoromethylsilicon tris(dialkylamide) CF₃Si(NMe₂)₃ (VI) in high yields.

(iii) Hydride and organometallic derivatives

Reduction of I with $LiAlH_4$ proceeded in the same way as that of CF_3SiF_2I [4], and CF_3SiH_3 was obtained in high yield. Similarly, MeMgBr and PhLi afforded the known species CF_3SiMe_3 [1] and the novel triphenyl derivative CF_3SiP_3 (VII).

(iv) Complex formation

The formation of the bis(pyridine) adduct II has been mentioned previously.

$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	Compound	B.p. (M.p.) ([∞] C / Torr)(([∞] C))	(mqq) (H1)&)/(HF) (Hz)	$\delta(^{14}F)$ (ppm)	⁽ J(F ^{IS} C) (Hz)	² J(F ²⁰ Si) (Hz)	⁷ J(FH) (Hz)	δ(¹³ C) (ppm)	1,(¹⁷ CF) (Hz)
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	CF,SiCI,	40.67753	A name of a managery particular source of the state of th	- I Linear and the second	- 70.5	314.7	76.2	 Provide a statistical and an and a statistical and a	123.6.q	314.3
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	CF ₃ SiH(NMe ₂) ₂	69/137	4.4,q (SiH)	3.85	- 63.8 d	322.3	44.6	3.95	129.5.q	322.2
CF ₃ SiOMe ₃ , 62.8/150 3.465.7 315.5 53.6 (V) CF ₃ SiNMe ₂), 60.6/17 2.3 59.1 324.4 41.0 (VI) (VI) (VI) (VI) (VI) (VI) (VI) (VI)	CF _S S(NCO) ₅	60.47/30	((117) 07		- 69.5	312.3	69,4			
V) CF _S S(NMe ₂) ₁ 60.6/17 2.3 59.1 324.4 41.0 (VI) (VI) (68-170) 7.0 57.4 322.9 38.1 VI)."	CF _a Si(OMe) _a Via	62.8//150	4		- 65,7	315,5	53.6			
V1) CF_SIPh ₃ ((68–170) 7.0 57.4 322.9 38.) V10."	CF,Si(NMe ₂) ₁	60.6717	F		1.63	324.4	41,0			
	(VJ) CF ₅ SiPh ₃ VII)"	((68-170)	0.7		57.4	322.9	38.1			

PHYSICAL PROPERTIES AND NMR SPECTRA OF COMPOUNDS I AND HETO VIL

TABLE I



Fig. 1. IR spectrum of I: A: 10 cm cell, KBr windows, 3 mbar, resolution 1-2 cm⁻¹. B: 18 cm cell, polythene windows, 12 mbar, resolution 2-4 cm⁻¹. C: 18 cm cell, polythene windows, 30 mbar, resolution 1 cm⁻¹. Rotational lines of HCl are marked by an asterisk.

Formation of a dipyridyl complex $CF_3SiCl_3 \cdot bipy$ (VIII), presumably with *cis* configuration has been demonstrated.

To sum up, I undergoes a variety of reactions typical of $SiCl_4$ and $RSiCl_3$ without attack on the CF₃Si moiety. Cleavage of the Si-C bond is however observed in the presence of aqueous alkali and at elevated temperature. Thus, I, and its



Fig. 2. Raman spectrum of I: 1 mm o.d. capillary, slit width 4 cm^{-1} , parallel and perpendicular polarization.

derivatives are versatile starting materials for the synthesis of a variety of trifluoromethylsilicon derivatives.

Spectra

The new compounds I and III to VII were characterized by their ¹⁹F NMR spectra (Table 1). The complexes dissociate in solution, and so give the NMR spectra of the constituents. The H, CH_3 and F derivatives were identified by means of their known ¹⁹F NMR spectra. In addition the ¹H NMR data for HI and V to VII and the ¹³C data of I and HI are given in Table 1. The ² $J(F^{29}Si)$ coupling constant varies from 76.2 to 38.1 Hz, and the variation seems to be correlated with the fluorine chemical shift. For some of the compounds the mass spectra have also been recorded, and selected m/e peaks are noted in the experimental section.

Because of the expected analogy with $SiCl_4$ and $SiCl_3Br$, the vibrational spectrum of I was evaluated in greater detail, and a normal coordinate analysis performed. The IR and Raman spectra are displayed in Fig. 1 and 2, and numerical data are set out in Table 2.

TABLE 2

INFRARED AND RAMAN SPECTRA OF CF	.SiC	1
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IR, gas	Raman, liquid	Assignment
103.5w	1105	$\nu_{12}, \rho(\mathrm{SiCl}_2)$
107.5w		
176m	1788	$v_5, \delta_5(\operatorname{SiCL}_3); v_{13}, \delta_{10}(\operatorname{SiCL}_3)$
277.7m	280m	$\nu_0, \rho(CF_3)$
3658	364vs p	$r_3, r(SiC)$
469w		$107.5 \pm 365 = 472.5$
	525w	$\nu_8, \nu_{\alpha8}$ (CE ₃)
5385	532s p	v_A , v_S (SiCl ₃)
640vs	ň	
646vs	63.7w	$\nu_{10}, \nu_{\alpha}(\mathrm{SiCL}_3)$
710w		176 + 538 = 714
747m. PQR	745sp	$\nu_{\pi_{\lambda}} \delta_{\lambda} (CE_{\lambda})$
809w		277.7 ± 538 ± 815.7 (HSiC1 ₃ ?)
818wsh		$176 \div 646 \approx 822$
852w		107.5 - 747 = 854.5
902w		$365 \pm 538 = 903$
1027w		277.7 + 747 - 1024.7
1098m.)		
1130vs Ĵ	1118w	$\boldsymbol{\nu}_{2}, \boldsymbol{\nu}_{22} (\mathrm{CF}_{2})^{\pm 2} \mathrm{C}^{\pm 12} \mathrm{C}^{\pm 12} \mathrm{C}^{\pm 12}$
1167w		$525 \pm 646 = 1171$
1183w (
12185)	1215w.p	$\nu_1, \nu_1(C\Gamma_3)^{-13}C_1^{-12}C_2$
1272m		525 - 747 - 1272
1321vw		$107.5 \pm 1218 = 1325.5$
1402w		277.7 + 1130 = 1407.7
1495w		277.7 - 1218 = 1495.7
1655w		$525 \pm 1130 = 1655$
1740w		525 × 1218 = 1743
1870m		747 + 1130 = 1877
1962w		$747 \pm 1218 = 1968$

On the assumption of C_{3v} symmetry, CF_3SiCl_3 exhibits 5 a_1 and 6 e vibrations, and in addition an inactive a_2 torsion which was not observed. The inner vibrations of the CF_3 group, $\nu_1(a_1)$ 1218 cm⁻¹, $\nu_2(a_1)$ 747 cm⁻¹, $\nu_7(e)$ 1130 cm⁻¹ and $\nu_8(e)$ 525 cm⁻¹ appear in the expected regions. The CF_3 rocking mode $\nu_9(e)$, 278 cm⁻¹, is closer to that in CF_3Br , 303 cm⁻¹ [9] than that in CF_3SiH_3 , 217 cm⁻¹ [5], because of repulsion by ν_{11} and ν_{12} . The vibrations $\nu_3-\nu_5$ and $\nu_{10}-\nu_{12}$ correspond closely to those of SiCl₃Br, and are related to those of SiCl₄ [10]:

		CF ₃ SiCl ₃	SiCl ₃ Br		SiCl ₄	_
$\overline{a_1}$	ν,	365	368	<i>a</i> ₁	424	
	ν_4	538	545	e	150	
	V 5	176	190	f_2	608	
е	$\boldsymbol{\nu}_{10}$	646	610	_	221	
	P ₁₁	176	205			
	ν_{12}	106	135			

The assignment of the observed vibrational transitions is therefore straightforward. PQR structure was only observed for $\nu_2(a_1)$ and $\nu_{12}(e)$. Owing to the

TABLE 3

MAIN INNER FORCE CONSTANTS OF I, CF₃SiH₃ AND SiCl₄ SCALED TO 1 Å (N cm⁻¹)

	CF ₃ SiCl ₃	CF ₃ SiH ₃ [5]	SiCl ₄ [11]	
SiC	2.899	2.537		
SiC1	3.383		3.37(4)	
CF	5.818	5.602		
CF/CF'	0.967	0.936		
SiC1/SiC1'	0.125		0.12(2)	
CF/SiC	0.158	0.150		
SiCl/SiC	0.122			
α-αα	1.515	1.512		
β-ββ	0.671	0.545		
Y-Y Y	0.720		0.77(2)	
δ-δδ	0.596			

TABLE 4

POTENTIAL ENERGY DISTRIBUTION (ONLY CONTRIBUTIONS $\geq 15\%$) OF NORMAL MODES OF CF₃SiCl₃

44(CF), 26(SiC), 24(α), 15(CF/CF')
$33(CF), 18(SiC), 17(\alpha)$
32(SiC), 32(SiCl)
63(SiCl), 21(SiC)
$41(\gamma), 30(\delta)$
$122(CF), 24(\alpha), -20(CF/CF')$
87(α)
66(β)
103(SiCl)
$87(\gamma), 21(\beta)$
$91(\delta), 21(\gamma), 17(\beta)$

presence of two Cl isotopes, some absorption bands show complex envelopes, e.g. v_{10} near 640 cm⁻¹. Furthermore, the presence of hot bands perturbs the band contours.

We have performed a normal coordinate analysis assuming the following geometry: SiC 1.900 Å, SiCl 2.019 Å, CF 1.348 Å, angle FCF $107.9^{\circ}(\alpha)$, FCSi $111.0^{\circ}(\beta)$, ClSiCl(γ) and ClSiC(δ) 109.47°. Force constants of the SiCl₃ part were taken to be the same as for SiCl₄ [11] and those for the CF₃Si fragment the same as for CF₃SiH₃ [5], and values were then refined to fit the observed wavenumbers exactly by use of a computer program [12]. The main inner force constants for 1 are listed in Table 3. and compared with those of CF₃SiH₃ [5] and SiCl₄ [11]. Table 4 gives the potential energy distribution in terms of inner force constants.

The SiC stretching force constant of I, which reflects the strength of the SiCF₃ bond, lies between that of CF₃SiH₃ and CH₃SiCl₃, 3.35 N cm⁻¹ [13]. This is what one would expect from taking account of atomic charges [14] and inductive effects.

Experimental

(*Trifluoromethyl)bis(dimethylamino)silane (III).* A pressure of 35 mbar CF₃Br was maintained as 213 g (861 mmol) P(NEt₂)₃ was added to a solution of 107.6 g (705 mmol) HSi(Cl)(NMe₂)₂ in 500 ml C₆H₅CN at 0°C during 1 h. The mixture was then brought to room temperature with vigorous stirring and the vessel charged with gaseous CF₃Br for 2.5 h. Then volatile material was distilled off at 50°C and 4 mbar and collected in a -78°C trap. Impurities (< 5%) were removed by fractional distillation through a a slit tube column, to give I in 86% yield. Elemental analyses are given in Table 5. Selected IR absorptions: 2168s (ν (SiH)), 1308s (δ (CH₃)), 1224s (ν_s (CF₃)), 1082vs (ν_w (CF₃)), 1004vs (ν_s (NC₂)), 858s cm⁻¹ (δ (SiH)). MS:

TABLE 5
ELEMENTAL ANALYSES

Compound	Formula	Analyses (Found (calcd.)(%))				
		C	Н	Cl	F	N
I	CCl ₃ F ₃ Si	6.0	< 0.2	52.0	27.5	**************************************
		(5.90)	(0.0)	(52.28)	(28.01)	
II	$C_{11}H_{10}CI_3F_3N_2Si$	36.4	3.2			7.8
		(36.53)	(2.79)			(7.75)
111	C ₅ H ₁₃ F ₃ N ₂ Si	32.5	7.1		31.0	15.1
		(32.24)	(7.04)		(30.60)	(15.04)
IV	C4F3N3O3Si	21.6	< 0.2		25.6	
		(21.53)	(0.0)		(25.54)	
V	C ₄ H ₉ F ₃ O ₃ Si	25.6	4.8		29,8	
		(25.26)	(4.77)		(29,97)	
VI	C ₂ H ₁₈ F ₃ N ₃ Si	36.7	7,7		25.1	18.2
		(36.66)	(7.91)		(24.85)	(18.32)
VII	$C_{19}H_{14}F_3Si$	71.1	4.9		17.0	
		(69.49)	(4.60)		(17.35)	
VIII	C ₁₁ H ₈ F ₃ Cl ₃ N ₅ Si	36.4	2.4			7.6
		(36.73)	(2.24)			(7.79)

 $m/e = 186 (M)^+$, 55%; 117 (SiH(NMe₂)₂)⁺, 100%; 92(F(H)SiNMe₂)⁺, 47%; 74 (H₂SiNMe₂)⁺, 45%; 44 (NMe₂)⁺, 64%.

(*Trifluoromethyl*)trichlorosilane (I). (a) 35 g HCl was condensed into a solution of 31.3 g (168 mmol) III in 1 l dibutyl ether at -78° C. The mixture was slowly warmed to room temperature, volatile products were boiled off at 55°C and 40 mbar, and the crude product collected in a -140° C trap. After distillation under reduced pressure (<500 mbar) through a slit-tube column a yield of 79% was obtained. MS: m/e = 137/135/133 (SiCl₃)⁺, 33/100/100%; 119/117 (FSiCl₂)⁺, 26/27%; 63 (SiCl)⁺, 35%.

(b) Under argon 29.8 g (200 mmol) CF_3Br was condensed into a solution of 34 g (200 mmol) $SiCl_4$ in 50 ml CH_2Cl_2 at $-78^{\circ}C$ and a solution of 49.5 g (200 mmol) $P(NEt_2)_3$ in 35 ml CH_2Cl_2 was added. The mixture was slowly warmed to room temperature and volatile products were then distilled off as the temperature was raised to 75°C. 5.0 g (63.2 mmol) pyridine was added to 14.3 g of the volatile products, the precipitate II filtered off, washed with ether, and dried in vacuo. An excess of HCl was condensed on to II at $-90^{\circ}C$ and the volatile products were collected; I was obtained by fractional condensation in vacuo in ca. 50% yield.

(*Trifluoromethyl*)trichlorosilane-2-pyridine (11). II was also obtained from pure I and pyridine in 91% yield. (II may be sublimed in vacuo at ca. 50°C, but then the product shows a slight deficiency of pyridine (composition ca. I · 1.8 pyridine)). MS: m/e = 135/133 (SiCl₃)⁺, 15/15%; 79 (C₅H₅N)⁺, 100%; 52 (C₄H₄)⁺, 78%; 51 (C₄H₃)⁺, 27%; 50 (C₄H₂)⁺, 16%.

(*Trifluoromethyl*)trichlorosilane-2,2'-bipyridyl (VIII). I (0.85 g, 4.2 mmol) was added to a solution of 2,2'-bipyridyl (0.74 g, 4.7 mmol) in 10 ml ether, and the resulting solution was filtered, washed, and dried, to give VIII in 93% yield. (VIII may be sublimed in vacuo at 80°C, but the product then contains an excess of 2,2'-dipyridyl.) MS: $m/e = 158 (C_{10}H_8N_2)^+$, 100%; 157 $(C_{10}H_7N_2)^+$, 40%; 135/133 (SiCl₃)⁺, 33%; 128 $(C_8H_4N_2)^+$, 20%.

(*Trifluoromethyl*)triisocyanatosilane (*IV*). I (0.37 g, 1.82 mmol) was condensed onto AgOCN (1.5 g, 10 mmol) and the mixture was warmed to room temperature with vigorous shaking. Then volatile products were collected in vacuo and purified by fractional condensation, yield 88%. IR: 2320s, 2290vs (ν_{as} (NCO)), 1473s (ν_{s} (NCO)), 1234s (ν_{s} (CF₃)), 1117vs (ν_{as} (CF₃)), 748vs (ν_{as} (SiN₃)), 625s cm⁻¹ (δ (NCO)). MS: m/e = 154 (Si(NCO)₃)⁺, 100%; 131 (SiF(NCO)₂)⁺, 35%; 112 (Si(NCO)₂)⁺, 22%; 70 (SiNCO)⁺, 15%.

(*Trifluoromethyl*)trifluorosilane. I (0.26 g, 1.28 mmol) was condensed onto SbF_3 (1.17 g, 6.54 mmol) and the mixture was shaken for 2 h. Volatile products were distilled off in vacuo and purified by fractional condensation in vacuo. CF_3SiF_3 , yield 67%, was identified from its IR spectrum [3].

(*Trifluoromethyl*)trimethoxysilane (V). I (3.18 g, 15.6 mmol) was added to 2 ml CH₃OH at 0°C and the mixture was stirred for 30 min and the HCl then boiled off at 55°C. V and the excess of CH₃OH were separated by fractional condensation in vacuo, yield 90%. IR: 2990s, 2960s, 2865s (ν (CH₃)), 1252s (ν_s (CF₃)), 1200vs (ρ (CH₃)), 1150vs, 1123vs (ν (CO)), 1085vs (ν_{as} (CF₃)), 845s (ν_{as} (SiO₃)), 747s (ν_s (SiO₃)), 685s, 485s cm⁻¹. MS: m/e = 121 (Si(OMe)₃)⁺, 100%; 109 (FSi(OMe)₂)⁺, 26%; 91 (HSi(OMe)₂)⁺, 34%; 79 (F(H)SiOMe)⁺, 12%.

(Trifluoromethyl)tris(dimethylamino)silane (VI). I (3.78 g, 18.6 mmol) in 10 ml n-pentane was added to a solution of HNMe₂ (6 g, 133 mmol) in 50 ml n-pentane at

-78°C and the mixture kept at room temperature for several hours. The ammonium salt was filtered off and the solution distilled in vacuo, to give VI in 65% yield. IR: 1306s ($\delta_s(CH_3)$), 1216m ($\nu_s(CF_3)$), 1182s ($\rho(CH_3)$), 1071vs ($\nu_{as}(CF_3)$), 1001vs ($\nu_s(NC_2)$), 737s ($\nu_{as}(SiN_3)$), 622m cm⁻¹ ($\nu_s(SiN_3)$). MS: m/c = 229 (M)⁺, 14%; 160 (Si(NMe₂)₃)⁺, 100%; 135 (FSi(NMe₂)₂)⁺, 18%; 117 (HSi(NMe₂)₂)⁻, 23%; 92 (F(H)SiNMe₂)⁺, 16%.

(*Trifluoromethyl)silane.* 1 (3.0 g, 14.8 mmol) was condensed into a solution of LiAlH₄ (0.5 g, 13.2 mmol) in 150 ml dibutyl ether and the mixture was brought to room temperature then stirred for 15 min. Volatile products were then distilled off in vacuo and purified by fractional condensation in vacuo. CF_3SiH_3 , yield 90%, was identified from its IR spectrum [5].

(*Trifluoromethyl)trimethylsilane.* To a solution of I (0.47 g, 2.3 mmol) in 10 ml dibutyl ether, 4 ml of a 2 *M* solution of CH₃MgBr in dibutyl ether was added at 0°C. After 2 h stirring at room temperature, 10 ml of cold 3% aqueous HCl was added and the ether fraction worked up. CF₃Si(CH₃)₃, yield 85%, was identified from its NMR [1] and IR spectrum [15].

(*Trifluoromethyl*)triphenylsilane (VII). To a solution of 1 (1.37 g, 6.7 mmol) in 30 ml ether, 11 ml of a 2 *M* solution of phenyllithium in 3/1 C₆H₆/ether was added at -78° C and the mixture was stirred for 30 min at room temperature, and 20 ml of cold, aqueous HCl (10%) then added. Work-up gave colourless crystals of VII (from C₆H₆), yield 75%. IR (KBr): 1201 s (ν_{s} (CF₃)), 1060vs (ν_{as} (CF₃)). Phenyl vibrations (on Whiffen's notation [16]): 1430s (n), 1116s (q), 1029m (b), 997m (p), 741m (f), 717s (r), 697s (r'), 678m cm⁻¹ (v). MS: m/e = 328 (M)⁺, 0.3; 259 (SiPh₃)⁺, 100%; 181 (SiPhC₆H₄)⁺, 27%.

Spectra

IR: Perkin–Elmer 580 B, gaseous samples unless otherwise stated. FIR: Nicolet Series 8000 vacuum interferometer, resolution 1 cm⁻¹. Raman: Cary 82, excitation Kr⁺ 6471 Å. NMR: ${}^{1}\text{H}/{}^{19}\text{F}$ Varian EM 390, external standard TMS/CFCl₃. ${}^{13}\text{C}$ Varian FT 80, internal standard C₆D₆ 128.0 ppm. MS: MAT 311, E. I., 70 eV.

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